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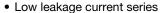
Vishay Semiconductors

# Power Silicon Rectifier Diodes, (Stud Version), 35 A, 40 A, 60 A



DO-5 (DO-203AB)

## **FEATURES**





Good surge current capability up to 1000 A

RoHS

 Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

A, 40 A, 60 A
-5 (DO-203AB)
Single

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	1N1183	1N3765	1N1183A	1N2128A	UNITS
1		35 <sup>(1)</sup>	35 <sup>(1)</sup>	40 <sup>(1)</sup>	60 <sup>(1)</sup>	Α
I <sub>F(AV)</sub>	T <sub>C</sub>	140 <sup>(1)</sup>	140 <sup>(1)</sup>	150 <sup>(1)</sup>	140 <sup>(1)</sup>	°C
1	50 Hz	480	380	765	860	^
IFSM	60 Hz	500 <sup>(1)</sup>	400 <sup>(1)</sup>	800 <sup>(1)</sup>	900 (1)	Α
I <sup>2</sup> t	50 Hz	1140	730	2900	3700	A <sup>2</sup> s
I-T	60 Hz	1040	670	2650	3400	A-S
I <sup>2</sup> √t		16 100	10 300	41 000	52 500	A <sup>2</sup> √s
V <sub>RRM</sub>	Range	50 to 600 <sup>(1)</sup>	700 to 1000 <sup>(1)</sup>	50 to 600 <sup>(1)</sup>	50 to 600 <sup>(1)</sup>	V
TJ		-65 to +200	-65 to +200	-65 to +200	-65 to +200	°C

#### Note

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS					
TYPE NUMBER	3		V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE (T <sub>J</sub> = -65 °C to +200 °C <sup>(2)</sup> ) V	$V_{RM}$ , MAXIMUM DIRECT REVERSE VOLTAGE (T <sub>J</sub> = -65 °C to +200 °C <sup>(2)</sup> ) V	
VS-1N1183	VS-1N1183A	VS-1N2128A	50 <sup>(1)</sup>	50 <sup>(1)</sup>	
VS-1N1184	VS-1N1184A	VS-1N2129A	100 (1)	100 (1)	
VS-1N1185	VS-1N1185A	VS-1N2130A	150 <sup>(1)</sup>	150 <sup>(1)</sup>	
VS-1N1186	VS-1N1186A	VS-1N2131A	200 (1)	200 (1)	
VS-1N1187	VS-1N1187A	VS-1N2133A	300 (1)	300 <sup>(1)</sup>	
VS-1N1188	VS-1N1188A	VS-1N2135A	400 (1)	400 (1)	
VS-1N1189	VS-1N1189A	VS-1N2137A	500 <sup>(1)</sup>	500 <sup>(1)</sup>	
VS-1N1190	VS-1N1190A	VS-1N2138A	600 <sup>(1)</sup>	600 <sup>(1)</sup>	
VS-1N3765	VS-1N2160		700 (1)	700 <sup>(1)</sup>	
VS-1N3766			800 (1)	800 (1)	
VS-1N3767			900 (1)	900 (1)	
VS-1N3768			1000 (1)	1000 (1)	

#### Notes

<sup>(1)</sup> JEDEC® registered values

Basic type number indicates cathode to case. For anode to case, add "R" to part number, e.g., 1N1188R, 1N3766R, 1N1186RA, 1N2135RA
JEDEC® registered values

 $<sup>^{(2)}</sup>$  For 1N1183 Series and 1N3765 Series  $T_C$  = -65  $^{\circ}$ C to +190  $^{\circ}$ C



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PARAMETER	SYMBOL	TEST CONDITIONS		1N1183	1N3765	1N1183A	1N2128A	UNITS
Maximum average forward current at case temperature	I <sub>F(AV)</sub>	1-phase operation, 180° sinusoidal conduction		35 <sup>(1)</sup> 140 <sup>(1)</sup>	35 <sup>(1)</sup> 140 <sup>(1)</sup>	40 <sup>(1)</sup> 150 <sup>(1)</sup>	60 <sup>(1)</sup>	A °C
		Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load	480	380	765	860	
Maximum peak one cycle	1	Half cycle 60 Hz sine wave or 5 ms rectangular pulse	condition and with rated V <sub>RRM</sub> applied	500 <sup>(1)</sup>	400 (1)	800 (1)	900 (1)	
non-repetitive surge current	I <sub>FSM</sub>	Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and	570	455	910	1000	А
		Half cycle 60 Hz sine wave or 5 ms rectangular pulse	with $\frac{1}{2}$ $V_{RRM}$ applied following surge = 0	595	475	950	1050	
		t = 10 ms	With rated V <sub>RRM</sub>	1140	730	2900	3700	
Maximum I <sup>2</sup> t for fusing	– I <sup>2</sup> t	t = 8.3 ms	applied following surge, initial $T_J = T_J$ maximum	1040	670	2650	3400	A <sup>2</sup> s
		t = 10 ms	With V <sub>RRM</sub> = 0 following surge, initial T <sub>J</sub> = T <sub>J</sub> maximum	1610	1030	4150	5250	A <sup>2</sup> S
Maximum I <sup>2</sup> t for individual device fusing		t = 8.3 ms		1470	940	3750	4750	
Maximum l <sup>2</sup> √t for individual device fusing	I²√t (2)	t = 0.1 to 10 ms, V <sub>RRM</sub> = 0 following surge		16 100	10 300	41 500	52 500	A²√s
Maximum peak forward voltage	V <sub>FM</sub>	T <sub>J</sub> = 25 °C		1.7 <sup>(1)</sup>	1.8 <sup>(1)</sup>	1.3 <sup>(1)</sup>	1.3 <sup>(1)</sup>	V
at maximum forward current (I <sub>FM</sub> )				110	110	126	188	Α
$V_{RRM} = 700$				-	5.0 <sup>(1)</sup>	-	-	
Maximum avorago		Maximum rated I <sub>F0</sub>	wa and To	-	4.0 <sup>(1)</sup>	-	-	
Maximum average reverse current $V_{RRM} = 900$	I <sub>R(AV)</sub>	maximum ratou i <sub>F()</sub>	-	3.0 (1)	-	-	mA	
V <sub>RRM</sub> = 1000				-	2.0 (1)	-	-	
		Maximum rated IF(	$_{AV)}$ , $V_{RRM}$ and $T_{C}$	10 <sup>(1)</sup>	-	2.5 <sup>(1)</sup>	10 <sup>(1)</sup>	

#### Notes

(1) JEDEC® registered values

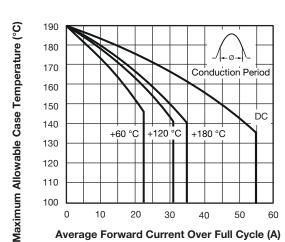
(2)  $I^2t$  for time  $t_x = I^2\sqrt{t} \times \sqrt{t_x}$ 

THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS 1N1183 1N3765 1		1N1183A	1N2128A	UNITS	
Maximum operating case temperature range	T <sub>C</sub>		-65 to +190 <sup>(1)</sup> -65 to +200		+200	°C	
Maximum storage temperature range	T <sub>Stg</sub>		-65 to	-65 to +175 <sup>(1)</sup> -65 to +200		+200	
Maximum internal thermal resistance, junction to case	R <sub>thJC</sub>	DC operation	1.0	1.00 (1) 1.1 (1)		0.65 (1)	°C/W
Thermal resistance, case to sink	R <sub>thCS</sub>	Mounting surface, smooth, flat and greased	0.25		C/VV		
		Not lubricated thread, tighting on nut (2)	3.4 (30)				
Maximum allowable		Lubricated thread, tighting on nut (2)		2.3	3 (20)		N·m
mounting torque (+ 0 %, - 10 %)		Not lubricated thread, tighting on hexagon (3)	4.2 (37)			(lbf · in)	
(		Lubricated thread, tighting on hexagon (3)		3.2	2 (28)		
Annyayimata waisht			17			g	
Approximate weight					0.6		oz.
Case style		JEDEC®		DO	-5 (DO-203	AB)	

#### Notes

- (1) JEDEC registered values®
- (2) Recommended for pass-through holes
- (3) Recommended for holed threaded heatsinks

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Fig. 1 - Maximum Allowable Case Temperature vs. Average Forward Current, 1N1183 and 1N3765 Series

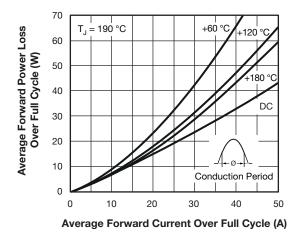


Fig. 2 - Typical Low Level Forward Power Loss vs. Average Forward Current (Sinusoidal Current Waveform), 1N1183 and 1N3765 Series

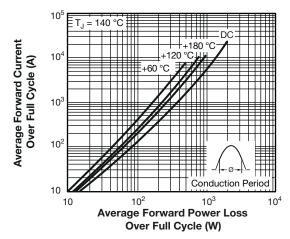


Fig. 3 - Typical High Level Forward Power Loss vs. Average Forward Current (Sinusoidal Current Waveform), 1N1183 and 1N3765 Series

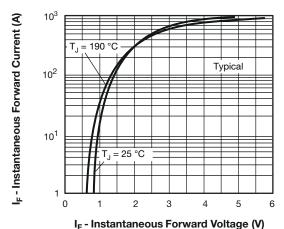


Fig. 4 - Typical Forward Voltage vs. Forward Current, 1N1183 and 1N3765 Series

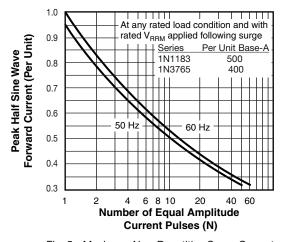
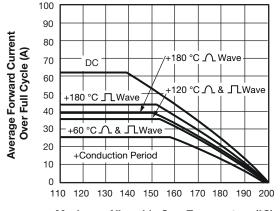


Fig. 5 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N1183 and 1N3765 Series



Maximum Allowable CaseTemperature (°C)

Fig. 6 - Average Forward Current vs. Maximum Allowable Case Temperature, 1N1183A Series



1.0

0.9

0.8

0.7

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Per Unit Base-A

At any rated load condition and with

rated V<sub>BBM</sub> applied following surge

↓ Series

1N1183A

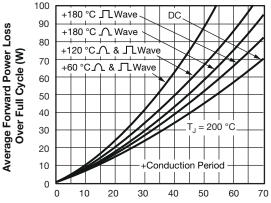
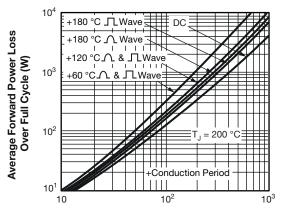


Fig. 7 - Maximum Low Level Forward Power Loss vs.

## Maximum Peak Half Sine Wave Forward Current (Per Unit) 0.6 50 H 0.4 0.3 8 10 **Number of Equal Amplitude** Average Forward Current Over Full Cycle (A) **Current Pulses (N)** Fig. 10 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N1183A Series Average Forward Current, 1N1183A Series



## Average Forward Current Over Full Cycle (A)

Fig. 8 - Maximum High Level Forward Power Loss vs. Average Forward Current, 1N1183A Series

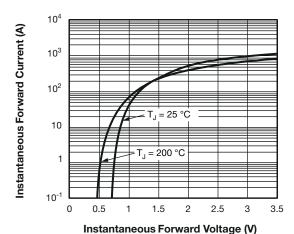


Fig. 9 - Maximum Forward Voltage vs. Forward Current, 1N1183A Series

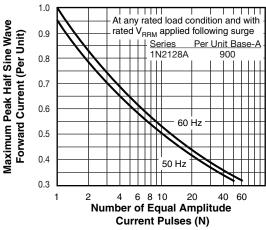


Fig. 11 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N2128A Series

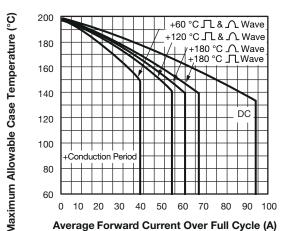


Fig. 12 - Maximum Allowable Case Temperature vs. Average Forward Current, 1N2128A Series

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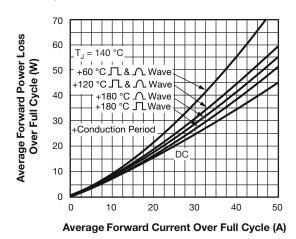
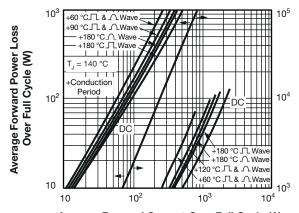


Fig. 13 - Maximum Low Level Forward Power Loss vs. Average Forward Current, 1N2128A Series



Average Forward Current Over Full Cycle (A)

Fig. 14 - Maximum High Level Forward Power Loss vs. Average Forward Current, 1N2128A Series

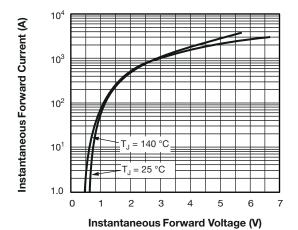


Fig. 15 - Maximum Forward Voltage vs. Forward Current, 1N2128A Series

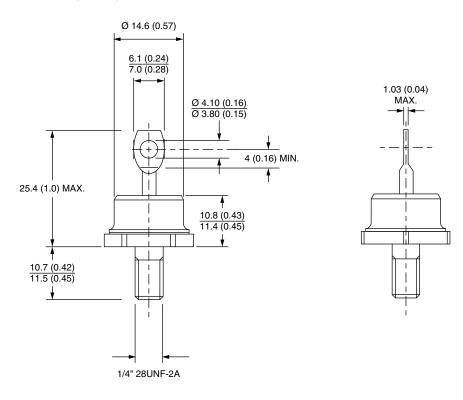
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95360				

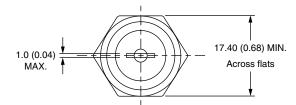


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# DO-203AB (DO-5) for 1N1183, 1N3765, 1N1183A, 1N2128A, 1N3208 Series

#### **DIMENSIONS** in millimeters (inches)







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